

Amplifier Transistor NPN Silicon

MPS4124

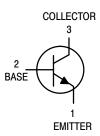
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CE}	25	Vdc
Collector-Base Voltage	V _{CB}	30	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current — Continuous	I _C	200	mAdc
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C



THERMAL CHARACTERISTICS

Characteristic	Symbol Max		Unit	
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W	



$\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}\text{C unless otherwise noted})$

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage (I _C = 1.0 mA, I _B = 0)	V _(BR) CEO	25	_	Vdc
Collector–Base Breakdown Voltage ($I_C = 10 \mu A, I_E = 0$)	V _(BR) CBO	30	_	Vdc
Emitter–Base Breakdown Voltage $(I_C = 0, I_E = 10 \mu A)$	V _{(BR)EBO}	5.0	_	Vdc
Collector Cutoff Current (V _{CB} = 20 V, I _E = 0)	I _{CBO}	_	50	nAdc
Emitter Cutoff Current $(V_{EB} = 3.0 \text{ V}, I_{C} = 0)$	I _{EBO}	_	50	nAdc

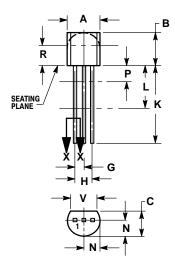
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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain $(I_C = 2.0 \text{ mA}, V_{CE} = 1.0 \text{ V})$ $(I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V})$	h _{FE}	120 60	360 —	_
Collector–Emitter Saturation Voltage ($I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$)	V _{CE(sat)}	_	0.3	Vdc
Base–Emitter Saturation Voltage ($I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$)	V _{BE(sat)}	_	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	-			
Current–Gain — Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V}, f = 100 \text{ MHz}$)	f _T	170	_	MHz
Output Capacitance $(V_{CB} = 5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$	C _{ob}	_	4.0	pF
Input Capacitance $(V_{EB} = 0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz})$	C _{ib}	_	13.5	pF
Small–Signal Current Gain ($I_C = 2.0 \text{ mA}, V_{CE} = 1.0 \text{ V}, f = 1.0 \text{ kHz}$)	h _{fe}	120	480	_
Noise Figure (I _C = 100 μ A, V _{CE} = 5.0 V, R _S = 1.0 k Ω , f = 1.0 kHz)	NF	_	5.0	dB

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		

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